



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Docket No. 252/013

#12

In re patent application of

Hi-Chun LEE

Serial No. 08/825,582

Filed: March 31, 1997

For: SUBSTRATE BIAS GENERATOR IN SEMICONDUCTOR MEMORY DEVICE

Group Art Unit: 2504

Examiner: Cunningham

REVOCATION OF POWER OF ATTORNEY

Commissioner for Patents
Washington, D.C. 20231

Sir:

Attached hereto is a Substitute Declaration/Power of Attorney for the above-identified application.

Applicants hereby revoke all previous Powers of Attorney.

Please change the correspondence address to:

Eugene M. Lee, Esq.

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JAN 22 2003

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JAN 21 2003

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Respectfully submitted,

Eugene M. Lee

Reg. No. 32,039

Richard A. Sterba

Reg. No. 43,162

January 17, 2003

Date

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SUBSTITUTE DECLARATION AND POWER OF ATTORNEY

I, below named inventor, I hereby declare that:

residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

IBSTRATE BIAS GENERATOR IN SEMICONDUCTOR MEMORY DEVICE

specification of which is attached hereto unless the following box is checked:

was filed on March 31, 1997 as United States Application Number or PCT International Application Number 08/825,582 and was amended on _____ (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is known by me to be material to patentability as defined in Title 37, Code of Federal Regulations 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) or § 365(b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have identified below any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed:

FOR FOREIGN APPLICATION(S)

NUMBER	COUNTRY	DAY/MONTH/YEAR FILED	PRIORITY CLAIMED
1994-1124	Republic of Korea	21/January/1994	Yes

I hereby claim the benefit under Title 35, United States Code § 119(e) of any United States provisional application(s) listed below.

APPLICATION NO.	FILING DATE

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is known by me to be material to patentability as defined in Title 37, Code of Federal Regulations § 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application:

APPLICATION SERIAL NO.	FILING DATE	STATUS: PATENTED, PENDING, ABANDONED
08/376,347	January 23, 1995	Abandoned
08/596,423	February 2, 1996	Abandoned
08/691,822	August 5, 1996	Abandoned

hereby appoint as my attorneys, with full powers of substitution and revocation, to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: Eugene M. Lee, Reg. No. 32,039; Richard A. Sterba, Reg. No. 43,162.

Address all correspondence to Eugene M. Lee, LEE & STERBA, PC, 1101 Wilson Boulevard, Suite 2000, Arlington, Virginia 22209. Address all telephone communications to Eugene M. Lee at (703) 525-0978.

hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full Name of First or Sole Inventor Hi-Chun LEE	Signature of First or Sole Inventor <i>Hi-Chun Lee</i>	Date <i>03/Jan/2003</i>
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Post Office Address Same as above		

252/013

LEE & STERBA, P.C.

Receipt is hereby acknowledged of the following:

In re patent application of

Hi-Chun LEE

Serial No. 08/825,582

Filed: March 31, 1997

For: SUBSTRATE BIAS GENERATOR IN SEMICONDUCTOR MEMORY DEVICE

☒ Revocation of Power of Attorney, Declaration/Power of Attorney

☒ Status Inquiry

